
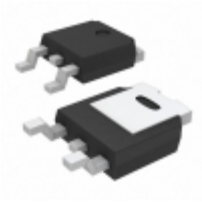

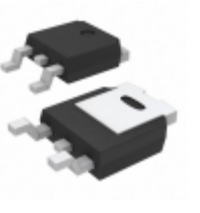
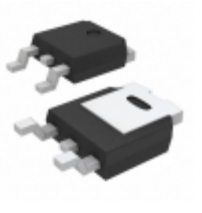
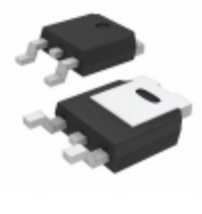
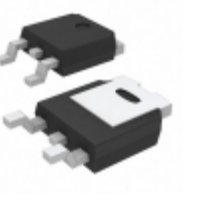
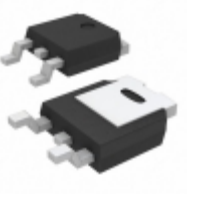

	<p>Hersteller-Teilenummer: STD11N65M5</p> <hr/> <p>Hersteller / Marke: STMicroelectronics</p> <hr/> <p>Teil der Beschreibung: MOSFET N CH 650V 9A DPAK</p> <hr/> <p>Datenblätter:  STD11N65M5.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 119194 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	<p>Image may be representation. See specs for product details.</p>

Spezifikationen

Teilenummer	STD11N65M5
Hersteller	STMicroelectronics
Beschreibung	MOSFET N CH 650V 9A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	119194 pcs Stock
Serie	MDmesh™ V
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	85W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	650V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	9A (Tc)
Rds On (Max) @ Id, Vgs	480 mOhm @ 4.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	620pF @ 100V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tape & Reel (TR)




































STD11N65M5 ist neu im Original, Suche STD11N65M5 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD11N65M5 STMicroelectronics mit Garantie und Vertrauen.
Anfrage STD11N65M5: Info@Y-IC.com

Sie können auch interessiert sein:

 STD11NM60ND STMicroelectronics MOSFET N-CH 600V 10A DPAK	 STD11N65M5 11NM65 ST STD11N65M5 11NM65 ST	 STD11N60M2-EP STMicroelectronics N-CHANNEL 600 V, 0.550 OHM TYP.,	 STD11N60DM2 STMicroelectronics N-CHANNEL 600 V, 0.26 OHM TYP.,
 STD11N50M2 STMicroelectronics MOSFET N-CH 500V 8A DPAK	 STD11NM60N STMicroelectronics MOSFET N-CH 600V 10A DPAK	 STD11N65M2 STMicroelectronics MOSFET N-CH 650V 7A DPAK	 STD116GK18B Sirectifier IGBT Modules

heiße Teile

Mehr

 STD10NF30	 STD10NM50N	 STD10NM60N	 STD10NM60ND	 STD10NM65N
 STD10P10F6	 STD10P6F6	 STD10PF06	 STD10PF06-1	 STD10PF06L
 STD10PF06T4	 STD110N8F6	 STD110NH02LT4	 STD116GK08	 STD116GK08B
 STD116GK12	 STD116GK12B	 STD116GK14	 STD116GK14B	 STD116GK16
 STD116GK16B	 STD116GK18	 STD116GK18B	 STD11N50M2	 STD11N65M2
 STD11NM50N	 STD11NM60N	 STD11NM60ND	 STD120N4F6	 STD120N4LF6
 STD123SF	 STD123UF	 STD125GK16	 STD12L01	 STD12L01A
 STD12N05LT4	 STD12N06	 STD12N06L	 STD12N06LT4	 STD12N06T4
 STD12N10L	 STD12N10L-TR	 STD12N50M2	 STD12N60M2	 STD12N65M5
 STD12NE06	 STD12NE06L-TR	 STD12NE06LT4	 STD12NE06T4	 STD12NF06-1

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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